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SN65EPT22D

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Datasheet of SN65EPT22D - BUFFER DUAL LVPECL 3.3V 8-SOIC

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SN65EPT22

SN65EPT22 3.3 V Dual LVTTL/LVCMOS to Differential LVPECL Buffer

Features

- Dual 3.3V LVTTL to LVPECL Buffer
- **Operating Range**
 - LVPECL V_{CC} = 3.0 V to 3.6 V With GND = 0 V
- Support for Clock Frequencies to 2.0 GHz (typ)
- 420 ps Typical Propagation Delay
- Deterministic HIGH Output Value for Open Input Conditions
- **Built-in Temperature Compensation**
- Drop in Compatible to MC100ELT23
- PNP Single Ended Inputs for Minimal Loading

Applications

- Data and Clock Transmission Over Backplane
- Signaling Level Conversion

Simplified Schematic

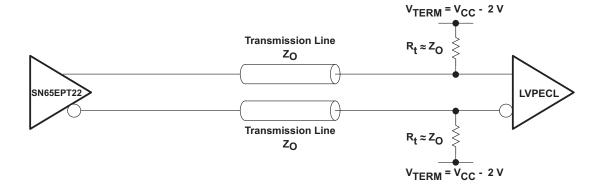
3 Description

The SN65EPT22 is a low power dual LVTTL to LVPECL translator device. The device includes circuitry to maintain known logic HIGH level when inputs are in open condition. The SN65EPT22 is housed in an industry standard SOIC-8 package and is also available in TSSOP-8 package option.

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)		
SN65EPT22	SOIC (8)	4.90mm x 3.91mm		
	VSSOP (8)	3.00mm x 3.00mm		

(1) For all available packages, see the orderable addendum at the end of the datasheet.





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5 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision A (November 2010) to Revision B	Page
Deleted the Ordering Information table	1
Added the Device Information table	1
Added the Simplified Schematic	1
Added the Handling Ratings	3
Added the Device and Documentation Support and Mechanical, Packaging, and Orderable Information	on 8
Changes from Original (November 2010) to Revision A	Page
Changed SN65EPT22 to EPT22 (2 places) in Ordering Information Table under Part Marking column	າ 1

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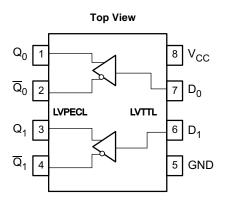


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6 Pin Configuration and Functions



Pin Functions

PIN	FUNCTION
D ₀ , D ₁	LVTTL data inputs
$Q_0, \overline{Q}_0, Q_1, \overline{Q}_1$	LVPECL outputs
V _{CC}	Positive supply
GND	Ground

7 Specifications

7.1 Absolute Maximum Ratings⁽¹⁾

PARAMETER	PARAMETER CONDITION				
Absolute supply voltage, V _{CC}			6	V	
Absolute input voltage, VI	Itage, VI $GND = 0$ and $VI \le V_{CC}$				
Supply voltage LVPEL			3.3	V	
	Continuous		50	mA	
Output current	Surge	Surge 10			
Operating temperature range			85	°C	

⁽¹⁾ Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

7.2 Handling Ratings

			MIN	MAX	UNIT	
T _{stg}	Storage temperature rang	Storage temperature range				
V	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins ⁽¹⁾	-4	4	kV	
V _(ESD)		Charged device model (CDM), per JEDEC specification JESD22-C101, all pins (2)	-2	2	ΚV	

⁽¹⁾ JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

⁽²⁾ JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



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7.3 Power Dissipation Ratings

PACKAGE	CIRCUIT BOARD MODEL	POWER RATING T _A < 25°C (mW)	THERMAL RESISTANCE, JUNCTION TO AMBIENT NO AIRFLOW	DERATING FACTOR T _A > 25°C (mW/°C)	POWER RATING T _A = 85°C (mW)
Ь	Low-K	719	139	7	288
D	High-K	840	119	8	336
DOK	Low-K	469	213	5	188
DGK	High-K	527	189	5	211

7.4 Thermal Information

	THERMAL METRIC ⁽¹⁾	D	DGK	LIMIT
THERMAL METRIC"		8 PINS	8 PINS	UNIT
$R_{\theta JB}$	Junction-to-board thermal resistance	79	120	°C/W
$R_{\theta JC}$	Junction-to-case thermal resistance	98	74	*C/VV

⁽¹⁾ For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.

7.5 Key Attributes

CHARACTERISTICS	VALUE
Moisture sensitivity level	Lead free package
SOIC-8	Level 1
VSSOP-8	Level 3
Flammability rating (Oxygen Index: 28 to 34)	UL 94 V-0 at 0.125 in
Meets or exceeds JEDEC Spec EIA/JESD78 latchup test	•

7.6 TTL Input DC Characteristics(1)

 $(V_{CC} = 3.3 \text{ V}, \text{ GND} = 0, T_A = -40^{\circ}\text{C to } 85^{\circ}\text{C})$

	CHARACTERISTIC	CONDITION	MIN	TYP	MAX	UNIT
I _{IH}	Input HIGH current	$V_{IN} = 2.7 \text{ V}$			20	μA
I _{IHH}	Input HIGH current max	$V_{IN} = V_{CC}$			100	μΑ
I _{IL}	Input LOW current	V _{IN} = 0.5 V			-0.6	mA
V_{IK}	Input clamp voltage	$I_{IN} = -18 \text{ mA}$			-1	V
V_{IH}	Input high voltage		2.0			V
V _{IL}	Input low voltage				0.8	V

⁽¹⁾ Device will meet the specifications after thermal balance has been established when mounted in a socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are assured only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

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7.7 PECL Output DC Characteristics⁽¹⁾

 $(V_{CC} = 3.3 \text{ V; GND} = 0.0 \text{V})^{(2)}$

CHARACTERISTIC		-40°C		25°C			85°C			LINUT	
		MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	UNIT
I _{CC}	Power supply current		39	45		42	47		45	50	mA
V _{OH}	Output HIGH voltage (3)	2155	2224	2405	2155	2224	2405	2155	2224	2405	mV
V _{OL}	Output LOW voltage (3)	1355	1441	1605	1355	1438	1605	1355	1435	1605	mV

- (1) Device will meet the specifications after thermal balance has been established when mounted in a socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are assured only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.
- (2) Output parameters vary 1:1 with V_{CC}
- (3) All loading with 50Ω to V_{CC} -2.0V

7.8 AC Characteristics (1)

 $(V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}; \text{ GND} = 0 \text{ V})^{(2)}$

CHARACTERISTIC			–40°C		25°C			85°C			UNIT
		MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	UNIT
f _{MAX}	Max switching frequency ⁽³⁾ , see Figure 5		2.1			2.0			2.0		GHz
t _{PLH} / t _{PHL}	Propagation delay to differential output	230		550	230		550	230		550	ps
4	Within device skew ⁽⁴⁾		25	50		25	50		25	50	ps
t _{SKEW}	Device to device skew ⁽⁵⁾		100	200		100	200		100	200	ps
t _{JITTER}	Random clock jitter (RMS)		0.2	8.0		0.2	8.0		0.2	8.0	ps
t_r / t_f	Output rise/fall times (20%-80%)	150		300	150		300	150		300	ps

- (1) Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are assured only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.
- Measured using a 2.4 V source, 50% duty cycle clock source. All loading with 50 Ω to VCC 2.0 V.
- Maximum switching frequency measured at output amplitude of 300 mV_{pp}. Skew is measured between outputs under identical transitions and conditions on any one device.
- Device-to-Device Skew for identical transitions at identical VCC levels.

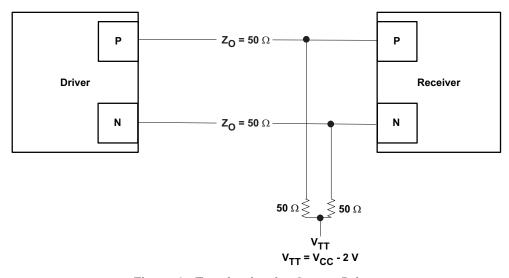


Figure 1. Termination for Output Driver

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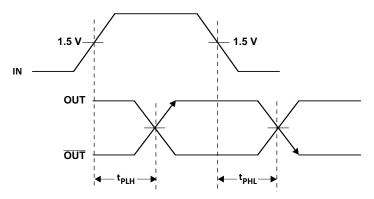


Figure 2. Output Propagation Delay

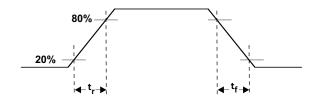


Figure 3. Output Rise and Fall Times

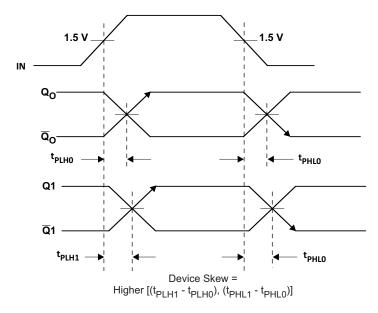


Figure 4. Device Skew

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Typical Characteristics

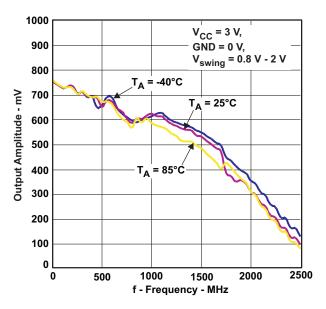


Figure 5. Output Amplitude versus Frequency



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8 Device and Documentation Support

8.1 Trademarks

All trademarks are the property of their respective owners.

8.2 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

8.3 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

9 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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PACKAGE OPTION ADDENDUM

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PACKAGING INFORMATION

Lead/Ball Finish Orderable Device Status Package Type Package Pins Package Eco Plan MSL Peak Temp Op Temp (°C) Device Marking Samples Drawing Qty (1) (2) (6) (3) (4/5)SN65EPT22D ACTIVE SOIC CU NIPDAU Level-1-260C-UNLIM EPT22 8 Green (RoHS D 75 -40 to 85 Samples & no Sb/Br) SN65EPT22DGK CU NIPDAU **ACTIVE** VSSOP DGK 80 Green (RoHS Level-1-260C-UNLIM SIQI 8 -40 to 85 & no Sb/Br) SN65EPT22DGKR ACTIVE VSSOP DGK 8 2500 Green (RoHS CU NIPDAU Level-1-260C-UNLIM -40 to 85 SIQI & no Sb/Br) SN65EPT22DR ACTIVE D 8 2500 Green (RoHS CU NIPDAU Level-1-260C-UNLIM -40 to 85 EPT22 & no Sb/Br)

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design. PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): Tl's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (6) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "-" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

Addendum-Page 1



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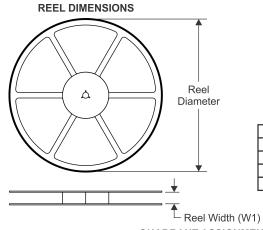
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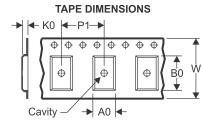


PACKAGE MATERIALS INFORMATION

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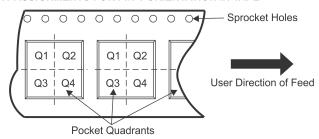
TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN65EPT22DGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
SN65EPT22DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1



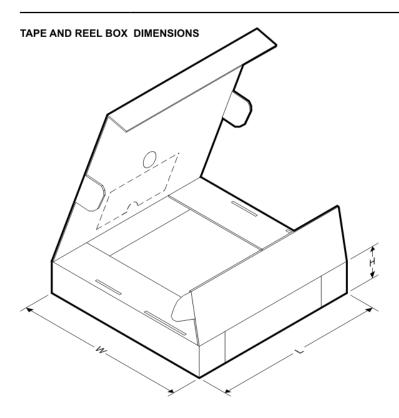
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*All dimensions are nominal

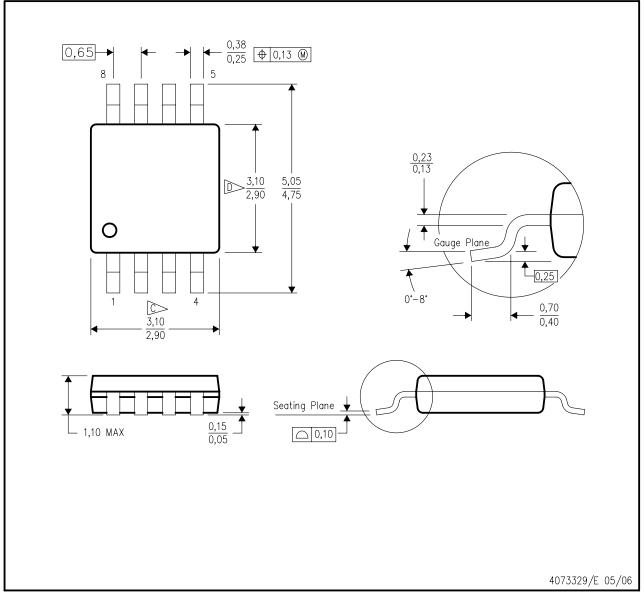
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN65EPT22DGKR	VSSOP	DGK	8	2500	367.0	367.0	35.0
SN65EPT22DR	SOIC	D	8	2500	367.0	367.0	35.0



MECHANICAL DATA

DGK (S-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 per end.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.50 per side.
- E. Falls within JEDEC MO-187 variation AA, except interlead flash.

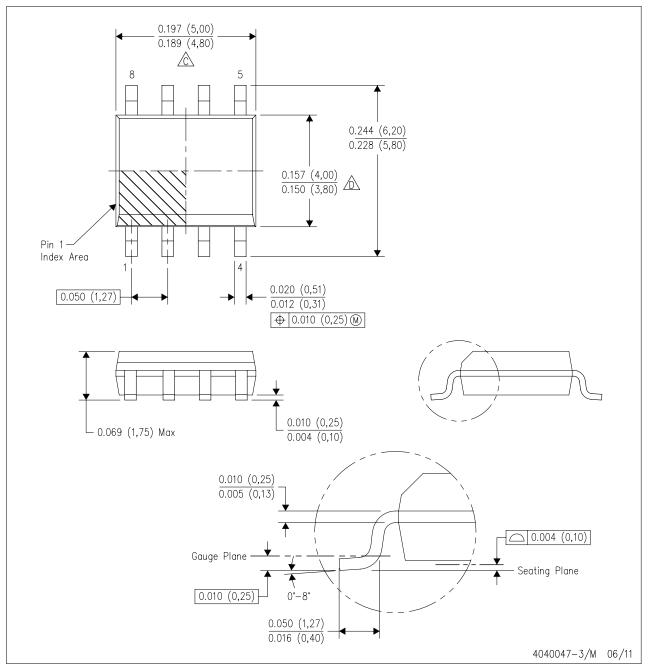




MECHANICAL DATA

D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AA.



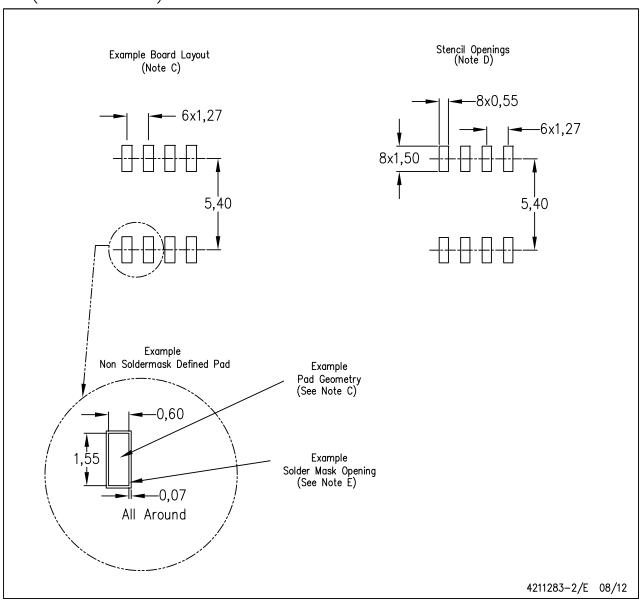




LAND PATTERN DATA

D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.





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